

1 **Superior energy storage properties in NaNbO₃-based ceramics via**
2 **synergistically optimizing domain and band structures**

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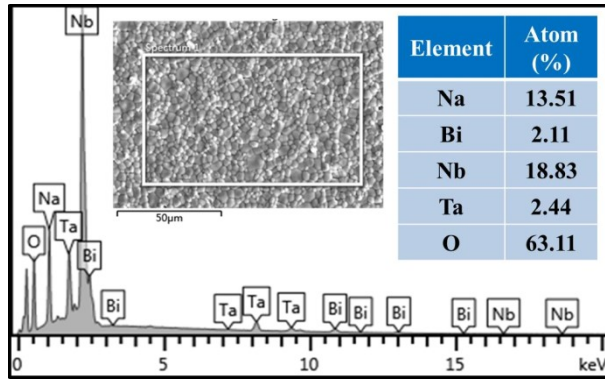


Figure S1 The EDS analysis of the NBNT10 ceramics.

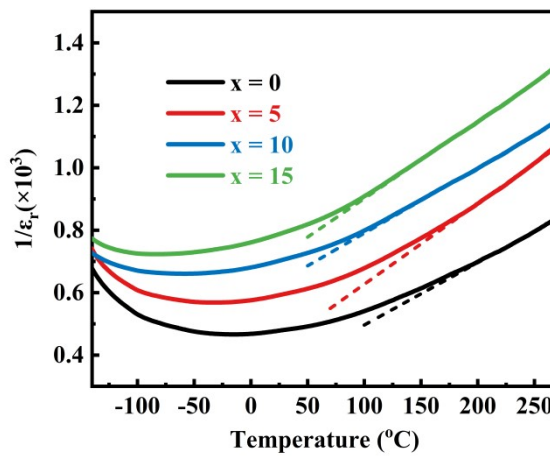


Figure S2 Temperature dependence of the reciprocal of dielectric constant at 10 kHz to determine the T_B values of the NBNT x ceramics.

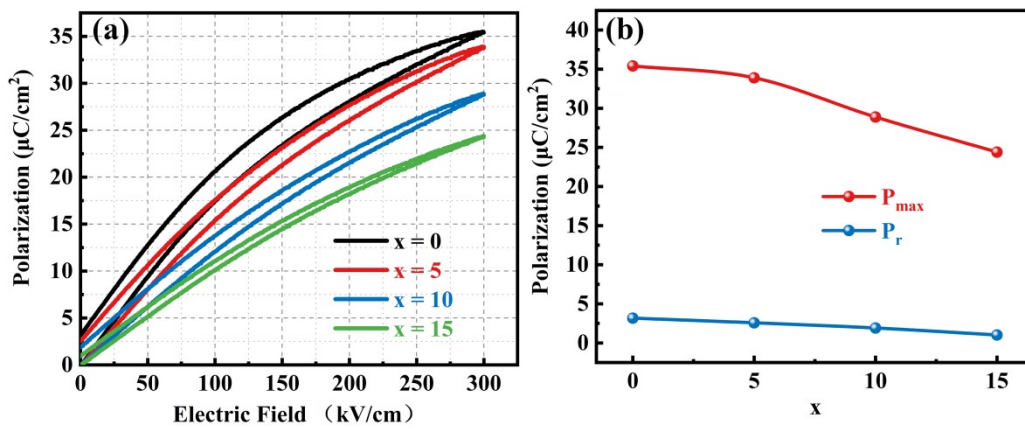
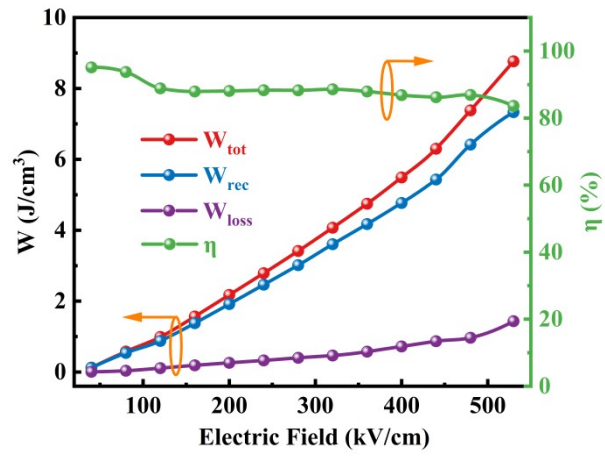


Figure S3 (a) P-E loops of the NBNT x ceramics at 300 kV/cm and 10 Hz; (b) The change of P_{max} and P_r with the variation of Ta content.



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2 Figure S4 Energy storage properties of the NBNT10 ceramics at different electric
 3 fields.